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Effect of N and B-doping on the electronic properties of 6,6,12-graphyne

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In this study we investigate the electronic properties of intrinsic and N and B-doping graphyne 6,6,12 using SIESTA code based on density functional theory. The results show that the intrinsic graphyne 6,6,12 is a semi-metal with Dirac cones between Γ to X' and at X symmetry point. Doping N

to the graphyne 6,6,12 changes it from semi-metal to a n-type semiconductor with indirect band gap. Doping B to the graphyne 6,6,12 changes it from semi-metal to metal. These results can be used in making high-performance nano-electronic components based on graphyne.

Biography

Amiri, Mohammad is working at Sharif University of Technology in Iran.

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